Growth and Application of High-T_c Whiskers

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We have succeeded in growth of high quality superconducting whiskers of Bi-2212 [1]. Further, Nagao developed Te-doped route which made it possible to grow Bi-22(n-1)n and RE-123 whiskers [2-4]. The dimensions of the whiskers, ~ 10 µm in width, ~ 1 µm in thickness and 1-15 mm in the length, are favorable to apply these single crystals to the various electrical and magnetic experiments, such as "intrinsic Josephson junctions (IJJ) by S-J. Kim [5]" and "cross whiskers junctions by Takano (c-plane twist junction) [6]". Among them, one of the most exciting target is a development of THz band oscillators. The intrinsic Josephson junctions were fabricated in these high-T_c whiskers by a 3-D focused ion beam etching method developed by S-J. Kim [5]. AC Josephson effect and resonance of square lattice Josephson flux-flow to the Josephson plasma predicted by Tachiki [7] was examined by current-voltage characteristics of these IJJs. On the former, we have applied for Bi-2212 and Y-123 inline IJJs and La-214 planer IJJ. On the latter, we have applied Bi-2212 inline IJJ. Besides, the oscillation in R-H curve corresponding to the width of the IJJ and triangular vortex lattice as reported by Ooi [8], we have observed oscillations in J_c-H curves corresponding to the square lattice at around 0.8 T. This result is a possible candidate for the realization of the prediction mentioned above. Multi branch spectrum showed a good agreement with the numerical experiments by Machida [9] in which four resonance stages were observed. At the magnetic field where J_c(H) takes minimum in its oscillation (H=0.81 T), multi-branch spectrum corresponding to the resonance of Josephson flux-flow to the Josephson plasma was observed. The voltage jump might be explained that the collective flux-flow of square lattice reached to the phase velocity of the Josephson plasma in Bi-2212 at much lower magnetic field than that reported by H-J. Lee [10].

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